

SPICE Device Model Si7658ADP

Vishay Siliconix

N-Channel 30-V (D-S) MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

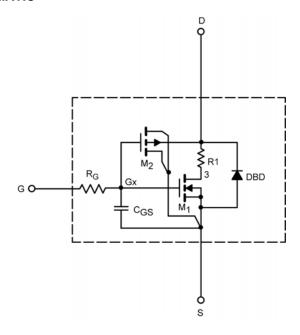
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the N-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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| SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED) | | | | | |
|--|--------------------------|--|-------------------|------------------|------|
| Parameter | Symbol | Test Condition | Simulated Data | Measured Data | Unit |
| Static | | | | | |
| Gate Threshold Voltage | $V_{_{\mathrm{GS(th)}}}$ | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 1.7 | | V |
| Drain-Source On-State Resistance | R _{DS(on)} | $V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$ | 0.0018 | 0.0018 | Ω |
| | | $V_{gs} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$ | 0.0024 | 0.0023 | |
| Forward Transconductance ^a | ${\sf g}_{\sf fs}$ | $V_{_{DS}} = 15 \text{ V}, I_{_{D}} = 20 \text{ A}$ | 131 | 100 | S |
| Diode Forward Voltage ^a | V _{SD} | I _s = 4 A | 0.75 | 0.72 | V |
| Dynamic⁵ | - | | | | |
| Input Capacitance | C_{iss} | $V_{_{OS}} = 15 \text{ V}, V_{_{GS}} = 0 \text{ V}, f = 1 \text{ MHz}$ | 4627 | 4590 | pF |
| Output Capacitance | C _{oss} | | 818 | 810 | |
| Reverse Transfer Capacitance | C _{rss} | | 237 | 320 | |
| Total Gate Charge | Q _g | $V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$ | 69 | 74 | nC |
| | | $V_{DS} = 15 \text{ V}, V_{QS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$ | 34 | 34 | |
| Gate-Source Charge | Q_{gs} | | 12 | 12 | |
| Gate-Drain Charge | Q_{gd} | | 10 | 10 | |

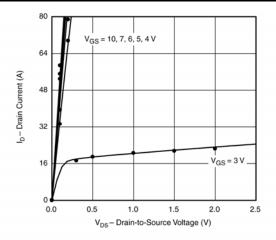
Notes a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

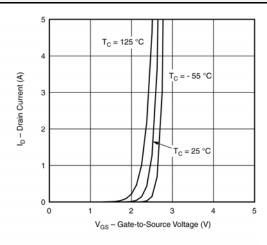


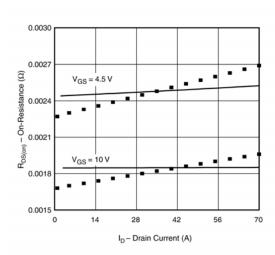
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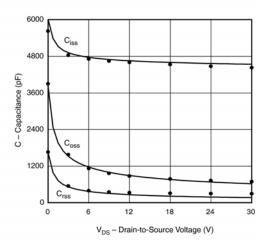
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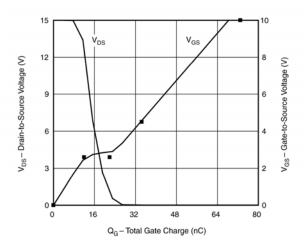
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C UNLESS OTHERWISE NOTED)

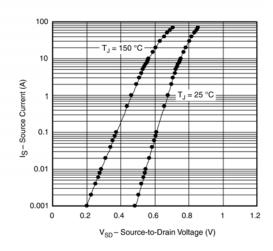














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